NSN 5961-01-466-3814

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-466-3814 **Inclosure Material:** Metal **Overall Length:** 0.255 millimeters **Terminal Length:** 0.180 millimeters **Overall Height:** 0.095 millimeters **Overall Width:** 0.155 millimeters **End Application:** Kok-22ae/ifscm12954 **Mounting Facility Quantity: Mounting Method: Bracket Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.0 reverse breakdown voltage, dc and 50.0 working peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 44.00 amperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 600.0 watts small-signal output power, common-base preset **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 175.0 degrees celsius case **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No